

Vishay General Semiconductor

AUTOMOTIVE GRADE

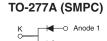
Available

COMPLIANT

HALOGEN FREE

High Current Density Surface Mount Ultrafast Rectifiers





PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 2.0 A				
V _{RRM}	100 V, 150 V, 200 V				
I _{FSM}	40 A				
t _{rr}	25 ns				
V _F at I _F = 2.0 A	0.77 V				
T _J max.	175 °C				

TYPICAL APPLICATIONS

high frequency rectification freewheeling application in switching mode converters and inverters for consumer computer, automotive, telecommunication applications.

FEATURES

- Very low profile typical height of 1.1 mm
- · Ideal for automated placement
- Oxide planar chip junction
- Ultrafast recovery times for high frequency
- · Low forward voltage drop, low power loss
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

MECHANICAL DATA

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and

automotive grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	UH4PBC	UH4PCC	UH4PCD	UNIT
Device marking code			H4BC	H4CC	H4DC	
Maximum repetitive peak reverse voltage		V _{RRM}	100	150	200	V
Maximum average forward rectified current (fig. 1)	total devive		4.0		А	
	per diode	I _{F(AV)}	2.0			
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	40		Α	
Operating junction and storage temperature range		T _J , T _{STG}	- 55 to + 175		°C	

Vishay General Semiconductor



ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 1.0 A	T 05 °C	V _F ⁽¹⁾	0.84	-	. V
	I _F = 2.0 A	$T_A = 25 ^{\circ}C$		0.93	1.05	
	I _F = 1.0 A	T _ 105 °C		0.68	-	
	I _F = 2.0 A	T _A = 125 °C		0.77	0.85	
Reverse current per diode	Poted V	T _A = 25 °C	I _R ⁽²⁾	-	5	μΑ
	Rated V _R	T _A = 125 °C		6.4	25	mA
Maximum reverse recovery time per diode	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A			20	25	ns
Typical reverse recovery time per diode	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 50 \text{ A/}\mu\text{s}, \\ V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$		t _{rr}	24	-	
Typical softness factor (t _b /t _a)per diode	I _F = 2 A, dl/dt = 200 A/μs, V _R = 200 V, I _{rr} = 0.1 I _{RM} T _A = 125 °C		S	0.3	-	-
Typical reverse recovery current per diode			I _{RM}	5.4	-	А
Typical stored charge per diode			Q _{rr}	88	-	nC
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	21	-	pF

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	UH4PBC	UH4PCC	UH4PCD	UNIT	
Typical thermal resistance per diode	R _{0JA} (1)	60			°C/W	
Typical thermal resistance per diode	$R_{ hetaJL}$	4			C/VV	

Note

(1) Units mounted on recommended PCB 1 oz. pad layout

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
UH4PDC-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel			
UH4PDC-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel			
UH4PDCHM3/86A (1)	0.10	86A	1500	7" diameter plastic tape and reel			
UH4PDCHM3/87A (1)	0.10	87A	6500	13" diameter plastic tape and reel			

Note

(1) Automotive grade



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RATINGS AND CHARACTERISTICS CURVES

 $(T_A = 25 \, ^{\circ}C \text{ unless otherwise noted})$

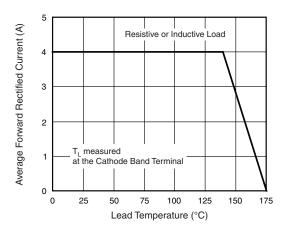


Fig. 1 - Maximum Forward Current Derating Curve

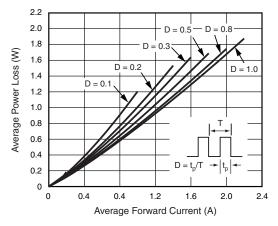


Fig. 2 - Forward Power Loss Characteristics Per Diode

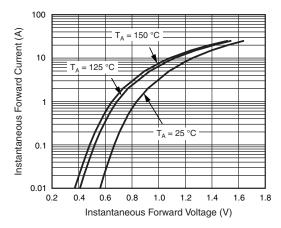


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

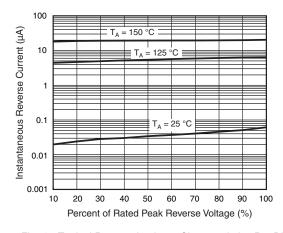


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

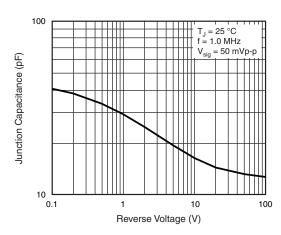


Fig. 5 - Typical Junction Capacitance Per Diode

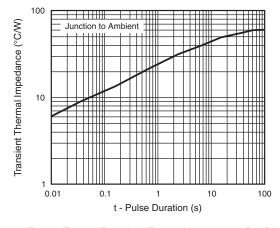
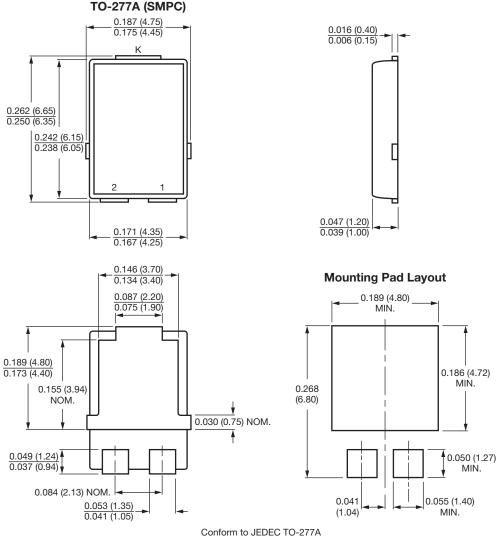


Fig. 6 - Typical Transient Thermal Impedance Per Diode

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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